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# Ultra-Miniaturised CMOS Current Driver for Wireless Biphasic Intracortical Microstimulation

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**Abstract**—This work shows an ultra-miniaturised and ultra-low-power CMOS current driver for biphasic intracortical microstimulation. The CMOS driver is composed of a leakage-based voltage-to-current converter and an H-bridge circuit providing biphasic charge-balanced current stimulation. The circuit has been simulated, fabricated and tested. The current driver consumes  $1.87 \mu\text{W}$  with a supply voltage of  $1.8 \text{ V}$ , and it occupies a silicon area of  $15 \times 12.4 \mu\text{m}^2$ . The driver works in linearity in the current range between  $23 - 92 \mu\text{A}$ .

**Keywords**— Analogue CMOS design; Bio/CMOS Interface; Biphasic Current Driver; Miniaturisation; Implantable Medical Device; Neural Implants.

## I. INTRODUCTION

Traditionally, brain microstimulation is performed in voltage or current mode. Since the tissue-electrode impedance changes over time, current stimulation is usually preferred to control the amount of charge delivered into the tissue. Therefore, current-controlled biphasic pulses are used to maintain charge balance across the electrode-tissue interface [1], [2].

Recently, many integrated circuits have been proposed for current-controlled microstimulation. In some cases, the focus was improving the circuit performance, such as voltage compliance, output current range (i.e., from dozens of  $\mu\text{A}$  to hundreds of  $\text{mA}$ ) and load balancing [3], [4]. In other cases, the aim was to increase the number of active channels driven by the implantable pulse generator [5]. Recent advances in neurotechnology focused on wireless microstimulation [6], [7], [8] and aimed at miniaturisation and power consumption reduction. Inductive Power Transfer (IPT) is a key player for both data and power transfer to extremely miniaturised wireless neural implants [9]. Although present solutions are highly performant in current modulation, they all require huge silicon area and high-power consumption [3], [5]. Therefore, they are inadequate for extremely miniaturised (i.e. smaller than  $1 \text{ mm}^3$ ) wireless neurostimulators. An ultra-miniaturised system has been proposed without a current driver, and the total current was delivered through the electrodes without amplitude modulation [6].

This paper shows an ultra-miniaturised and ultra-low-power CMOS current driver for wireless biphasic charge-balanced microstimulation with the possibility to modulate the current amplitude. The presented solution is based on a two-coil IPT

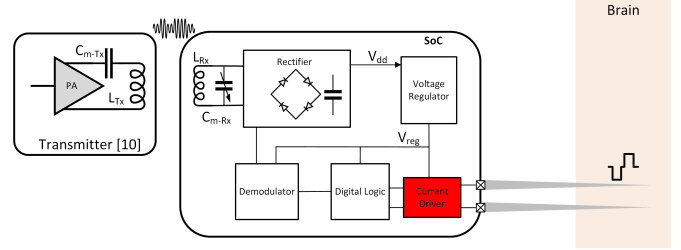


Figure 1: General scheme for an inductively coupled system, including the external transmitter [10] and the batteryless CMOS microstimulator. In red, the CMOS current driver proposed in this paper.

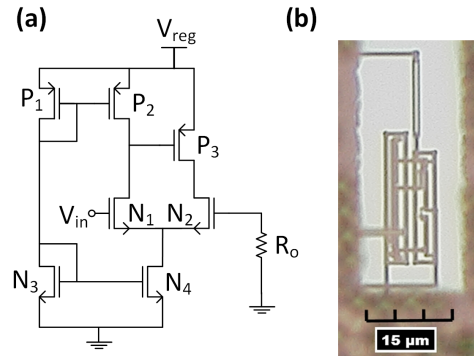


Figure 2: Leakage-based CMOS voltage-to-current converter (a) schematic and (b) chip micrograph.

link (Fig. 1). Being the implant wirelessly powered, both size and consumption of the CMOS must be minimised.

## II. METHODS

The circuit has been simulated at schematic and post-layout levels using Cadence IC6.1.7, with optimisations made to minimise area and power consumption. Post-layout simulations include the extraction (via Calibre) of parasitic resistances, capacitances and coupling-capacitances. The system has been fabricated using a TSMC 180-nm CMOS process and bonded in Quad Flat No-Lead (QFN) package. Measurements have been conducted after chip bonding, packaging and assembling in auxiliary testing-PCB (e.g., standard FR4 substrate,  $1.55 \text{ mm}$  thick). Control signals and supply voltages have been

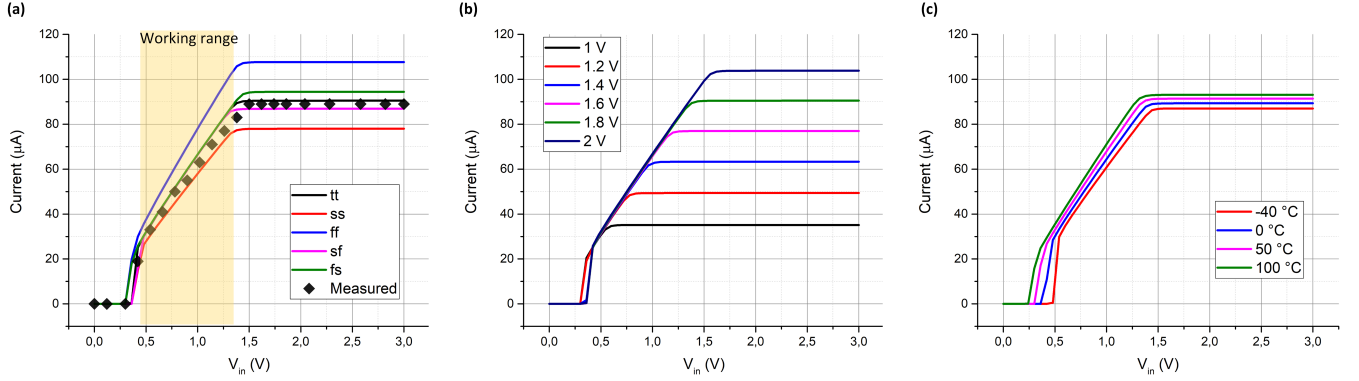


Figure 3: (a) Measurement of the I-V characteristic of the V-to-I converter compared with corner simulations (i.e., ss, ff, tt, sf and fs). The circuit works in linearity in the range  $23 - 92 \mu A$ . Simulations of the V-to-I converter characteristic under (b) supply voltage variation in the range  $1 - 2 V$  and (c) temperature variation in the range from  $-40 ^\circ C$  to  $100 ^\circ C$ .

injected respectively with a waveform generator (Keysight N5182B) and a DC power supply (Keysight E3646A). Output voltages and currents have been analyzed and extracted from oscilloscope (Keysight 4104A) and multimeter (Rohde&Schwarz HM8012).

### III. CMOS CURRENT DRIVER

The current driver is composed of a voltage-to-current converter and an H-bridge circuit to generate biphasic charge-balanced current pulses through the active and return micro-electrodes.

#### A. Voltage-to-current converter

Current is generated using a leakage-based voltage-to-current (V-to-I) converter [11], [12]. The V-to-I converter is based on leakage of transistor  $N_2$ , thus being an ultra-low power solution for ultra-miniaturised and wirelessly powered CMOS implants (Fig. 2-a). Moreover, the high output impedance [4] allows the mirroring of the output current that is then used to bias the H-bridge circuit to provide a biphasic stimulation across the two electrodes.

Fig. 2-b shows the micrograph of the V-to-I converter. Fig. 3-a compares the measured I-V characteristic of the V-to-I converter at  $1.8 V$  of supply with the post-layout corner simulation (i.e., ss, ff, tt, sf, fs). The small discrepancies between simulation and measurement are due to bonding, packaging and PCB-traces parasitic inductances and capacitances which were not considered during the simulation. The V-to-I converter consumes  $1.87 \mu W$  only at  $1.8 V$  of supply and it occupies a silicon area of  $7 \times 15 \mu m^2$ . It operates in linearity ( $R^2 = 0.9878$ ) for the input voltage  $V_{in}$  range  $0.45 - 1.4 V$  which corresponds to an output current of  $23 - 92 \mu A$ . Fig. 3-b shows the V-to-I converter dependence with the supply voltage in the range  $1 - 2 V$ . In particular, the supply voltage does not affect the linearity of the converter while it only limit the maximum deliverable output current. Finally, for the sake of completeness in the analysis of the Process-Voltage-Temperature (PVT) variations, the circuit

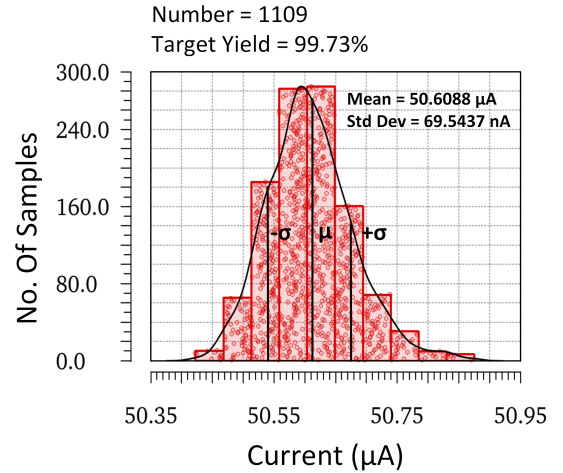


Figure 4: Monte Carlo analysis for  $50 \mu A$  of output current with a supply voltage of  $1.8 V$ .

is temperature-independent, as simulated by sweeping the temperature in the range from  $-40 ^\circ C$  to  $100 ^\circ C$  (Fig. 3-c).

Fig. 4 shows the Monte-Carlo study of the V-to-I converter supplied at  $1.8 V$  to deliver  $50 \mu A$  of output current. The latter has been selected since it is the value in the middle of the linear working range of the current driver. As a result, the robustness of the circuit is proven across process and transistor mismatch with a target yield of  $99.73\%$  and a standard deviation as small as less than  $70 nA$ .

#### B. H-bridge

Biphasic charge-balanced current stimulation is obtained through a couple of switches  $S_1$  and  $S_2$  to respectively drive cathodic and anodic pulses (Fig. 5-a). This solution also allows for a single current source  $I_{stim}$ , which is considered as a voltage-controlled current source, driven by the V-to-I converter. The direction of the flowing (state of the two couple of switches) is simply controlled by digital circuitry,

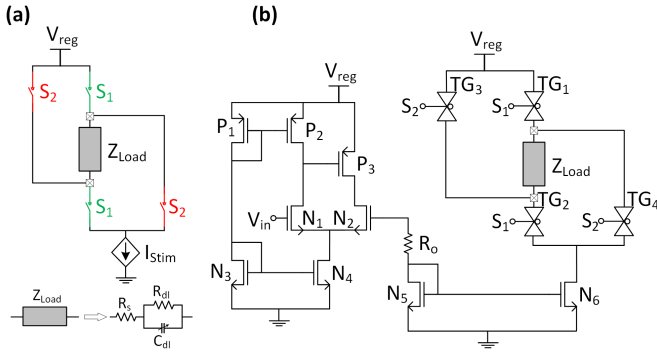


Figure 5: (a) Concept of H-bridge structure based on two couple of switches  $S_1$  and  $S_2$  to respectively drive cathodic and anodic stimulation (top) under the electrical equivalent load impedance (bottom). (b) Schematic of the entire CMOS current driver including the V-to-I converter, the current mirror and the TG-based H-bridge circuit.

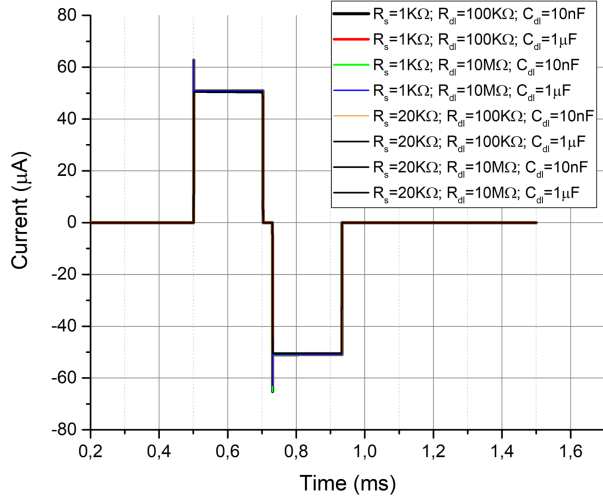


Figure 6: Transient performance of the entire current driver while delivering  $\pm 50 \mu A$  through the H-bridge circuit under different load conditions.

responsible for the time duration, pulse width and frequency of the stimulation pattern. The tissue-electrode interface  $Z_{load}$  has been translated into its electrical equivalent model [13], including the series tissue resistance  $R_s$  and the electrode-tissue interface modelled as a tank with a high resistance  $R_{dl}$  and a constant phase element here modelled as a single  $C_{dl}$ , whose capacitance value is dependent by the frequency. Reasonable values for all the component has been derived from in-vivo impedance spectroscopy studies involving penetrating microelectrodes [13]. Fig. 5-b shows the current driver, in which the current delivered by the V-to-I converter has been mirrored (through  $N_5$  and  $N_6$ ) to bias the fully CMOS H-bridge circuit [14]. Those elements occupy a silicon area of

$7 \times 11 \mu m^2$ . In particular, each switch is a PMOS/NMOS Transmission Gate (TG), allowing for extreme miniaturisation of the circuit while reducing the on-resistance of the switch. The two control signals  $S_1$  and  $S_2$  are externally synchronised and injected in the system, thus allowing the creation of different stimulation patterns. In particular, when  $S_1$  and  $S_2$  are closed (via  $TG_1 - TG_2$  and  $TG_3 - TG_4$ ) the cathodic and anodic pulses are respectively released across the two microelectrodes (through  $Z_{load}$ ).

The effect of  $Z_{load}$  variation on the delivered current waveform is particularly important to guarantee the system performances during time (i.e., the load impedance is known to change after first implantation [13]). Fig. 6 shows the transient performance of the entire circuit while delivering  $\pm 50 \mu A$  through the H-bridge circuit under different load conditions. In particular  $R_s$ ,  $R_{dl}$  and  $C_{dl}$  are respectively changed in the range  $1 - 20 k\Omega$ ,  $0.1 - 10 M\Omega$  and  $10 - 1000 nF$ . As a result, the current driver is robust and stable across all the load impedance variations.

The final measurement on the circuit is shown in Fig. 7, in which a  $500 Hz$  biphasic stimulation is obtained with a current amplitude of  $50 \mu A$  and two active phases of  $200 \mu s$  with a  $30 \mu s$  of inter-phase gap. As a result the circuit is capable to deliver  $\pm 50 \mu A$  under a  $10 k\Omega$  load resistor by alternatively externally activating  $S_1$  and  $S_2$ .

#### IV. DISCUSSION

The CMOS-based current driver occupies a silicon area of  $15 \times 12.4 \mu m^2$  while consuming  $1.87 \mu W$  driving  $\pm 50 \mu A$  with a supply voltage of  $1.8 V$ .

The circuit is strongly dependent on supply voltage variation (as in Fig. 3-b), meaning that its fluctuations are directly

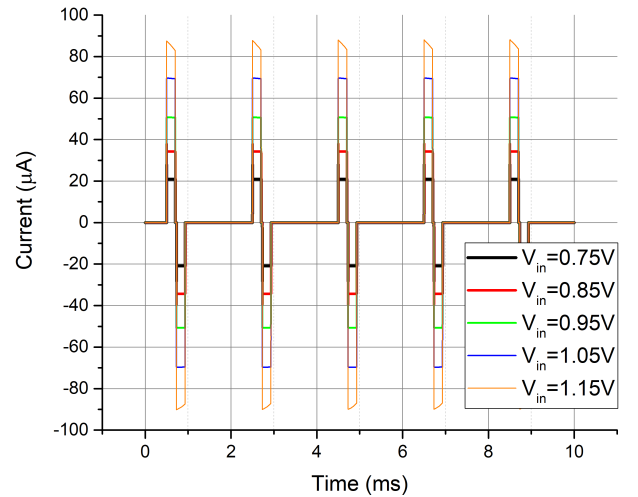


Figure 7: Measured current delivered by the circuit versus different input voltages under  $10 k\Omega$  resistor by alternatively activating  $S_1$  and  $S_2$  switches.

reflected into the maximum deliverable current. In the case of wirelessly powered implants, an on-chip rectifier and bypass capacitor are always used to translate Alternating Current (AC) input signals into Direct Current (DC) signals (i.e.,  $V_{dd}$  of Fig. 1).  $V_{dd}$  is therefore dependent on misalignment and variable coupling with the external transmitter. However, a Linear Dropout Regulator (LDO) is always used to ideally obtain a ripple-free regulated voltage ( $V_{reg}$ ). As an example, an LDO with a minimum power supply rejection of 42.7 dB (up at 50 kHz) and a line and load regulation of 0.5 mV/V and 1.05 mV/mA has been proposed [15]. Therefore, if  $V_{reg}$  is used to supply all the circuitry, the dependence of the V-to-I converter to the supply voltage is negligible. In our case, instead, the design choices and optimisations are made with the gaze turned toward both area and power consumption minimisation. Moreover, even if in the case of implanted neurostimulators the circuit-dependence on temperature is negligible (since the temperature varies within a small range), the proposed current driver is strongly temperature-independent (as in Fig. 3-c).

Our measurements have been conducted synchronising the signals from the external setup while in the future everything will be on-chip, thus enabling reliable in-vivo experiments with the integrated microelectrodes. The two signals  $S_1$  and  $S_2$  will be generated by a low frequency on-chip oscillator and managed by an opportune digital logic to create the final stimulation pattern (as in Fig. 1). Relaxation oscillators are capable of generating Hz-range periodic signals with extremely low silicon area (opportune sizing the capacitor and biasing the circuit) while reducing the power consumption [16].

The circuit is capable to deliver currents in the linear range between 23 – 92  $\mu$ A under different load conditions. Charge-balanced current pulses in this range are suitable for intracortical microstimulation. For example, it has been shown that the threshold to evoke phosphenes in the human visual cortex via intracortical microstimulation is in the order of 20 – 60  $\mu$ A [17].

## V. CONCLUSION

This paper presents a CMOS current driver for intracortical microstimulation. The circuit has been designed, optimised, realised and tested with area and power consumption as paramount specifications. The interface has been modelled and studied considering the impedance variation during time. Future work is required to integrate the microelectrodes with the CMOS chip, and investigate the circuit performance and robustness in-vivo. Nevertheless, our measurements already confirm that the current driver works in linearity in the range suitable for intracortical neurostimulation to evoke phosphenes in the human visual cortex.

## VI. ACKNOWLEDGMENT

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## REFERENCES

- [1] T. Wagner et al. “Biophysical foundations underlying TMS: setting the stage for an effective use of neurostimulation in the cognitive neurosciences”. In: *cortex* 45.9 (2009), pp. 1025–1034.
- [2] F. Mounaim and M. Sawan. “Miniature implantable system dedicated to bi-channel selective neurostimulation”. In: *2007 IEEE International Symposium on Circuits and Systems*. IEEE, 2007, pp. 2072–2075.
- [3] H. Kassiri et al. “Arbitrary-Waveform Electro-Optical Intracranial Neurostimulator With Load-Adaptive High-Voltage Compliance”. In: *IEEE Transactions on Neural Systems and Rehabilitation Engineering* 27.4 (2019), pp. 582–593.
- [4] M. Ghovanloo and K. Najafi. “A compact large voltage-compliance high output-impedance programmable current source for implantable microstimulators”. In: *IEEE Transactions on Biomedical Engineering* 52.1 (2004), pp. 97–105.
- [5] R. Shulyzki et al. “320-channel active probe for high-resolution neuromonitoring and responsive neurostimulation”. In: *IEEE transactions on biomedical circuits and systems* 9.1 (2014), pp. 34–49.
- [6] A. Khalifa et al. “The microbead: A 0.009 mm 3 implantable wireless neural stimulator”. In: *IEEE transactions on biomedical circuits and systems* 13.5 (2019), pp. 971–985.
- [7] J. Lee et al. “Neural recording and stimulation using wireless networks of microimplants”. In: *Nature Electronics* 4.8 (2021), pp. 604–614.
- [8] D. K. Piech et al. “A wireless millimetre-scale implantable neural stimulator with ultrasonically powered bidirectional communication”. In: *Nature biomedical engineering* 4.2 (2020), pp. 207–222.
- [9] G. L. Barbruni et al. “Miniaturised Wireless Power Transfer Systems for Neurostimulation: A Review”. In: *IEEE Transactions on Biomedical Circuits and Systems* 14.6 (2020), pp. 1160–1178.
- [10] G. L. Barbruni et al. “A 20 Mbps, 433 MHz RF ASK Transmitter to Inductively Power a Distributed Network of Miniaturised Neural Implants”. In: *2021 IEEE International Symposium on Medical Measurements and Applications (MeMeA)*. 2021, pp. 1–6.
- [11] B. Calvo et al. “A low-power high-sensitivity CMOS voltage-to-frequency converter”. In: *2009 52nd IEEE International Midwest Symposium on Circuits and Systems*. IEEE, 2009, pp. 118–121.
- [12] B. Fotouhi. “All-MOS voltage-to-current converter”. In: *IEEE Journal of solid-state circuits* 36.1 (2001), pp. 147–151.
- [13] S. F. Lempka et al. “In vivo impedance spectroscopy of deep brain stimulation electrodes”. In: *Journal of neural engineering* 6.4 (2009), p. 046001.
- [14] W. Ngamkham et al. “A 0.042 mm<sup>2</sup> programmable biphasic stimulator for cochlear implants suitable for a large number of channels”. In: *arXiv preprint arXiv:1502.00549* (2015).
- [15] N. Adorni, S. Stanzione, and A. Boni. “A 10-mA LDO with 16-nA IQ and operating from 800-mV supply”. In: *IEEE Journal of Solid-State Circuits* 55.2 (2019), pp. 404–413.
- [16] G. L. Barbruni et al. “Transistor Downscaling toward Ultra-Low-Power, sub-100  $\mu$ m<sup>2</sup> and sub-Hz Oscillators”. In: *SMACD / PRIME 2021; International Conference on SMACD and 16th Conference on PRIME*. 2021, pp. 1–4.
- [17] E. Fernández et al. “Visual percepts evoked with an intracortical 96-channel microelectrode array inserted in human occipital cortex”. In: *The Journal of Clinical Investigation* 131.23 (2021).